L Number	Hits	Search Text	DB	Time stamp
1	2826	361/56,58.ccls.	USPAT;	2004/11/08
			US-PGPUB;	13:32
			EPO; JPO;	
			DERWENT; IBM TDB	
2	1877	361/91.1,111.ccls.	USPAT;	2004/11/08
		•	US-PGPUB;	13:34
			EPO; JPO;	
			DERWENT; IBM TDB	
3	1598	361/117,119.ccls.	USPAT;	2004/11/08
			US-PGPUB;	13:35
			EPO; JPO;	
			DERWENT; IBM TDB	
4	385	327/313,314,325.ccls.	USPAT;	2004/11/08
			US-PGPUB;	13:36
ľ			EPO; JPO;	
			DERWENT; IBM TDB	
5	1636	257/357,360,364,365.ccls.	USPAT;	2004/11/08
			US-PGPUB;	13:37
			EPO; JPO;	
			DERWENT; IBM TDB	
_	162242	diode and transistor	USPAT;	2004/11/08
			US-PGPUB;	13:29
			EPO; JPO;	
			DERWENT; IBM TDB	
_	243	(diode and transistor) and n-mos adj1	USPAT;	2004/08/13
		transistor	US-PGPUB;	08:21
			EPO; JPO;	
			DERWENT; IBM TDB	
-	160	((diode and transistor) and n-mos adj1	USPAT;	2004/08/13
		transistor) and p-mos adj1 transistor	US-PGPUB;	09:40
			EPO; JPO; DERWENT;	
			IBM TDB	
_	0	ULP adj1 mos adj1 diode	USPĀT;	2004/08/13
			US-PGPUB;	09:41
			EPO; JPO; DERWENT;	
			IBM TDB	
-	621	mos adj1 diode	USPĀT;	2004/08/13
			US-PGPUB;	09:47
1			EPO; JPO; DERWENT;	
			IBM_TDB	
-	2787	361/56,58.ccls.	USPAT;	2004/08/13
			US-PGPUB; EPO; JPO;	09:48
			DERWENT;	
			IBM_TDB	
-	1840	361/91.1,111.CCLS.	USPAT;	2004/08/13
			US-PGPUB; EPO; JPO;	12:20
			DERWENT;	
		0.01/0.07 0.10 0.00 0.00	IBM_TDB	0004/00/12
-	1585	361/117,119.CCLS.	USPAT; US-PGPUB;	2004/08/13
			EPO; JPO;	12.37
			DERWENT;	
	_	2002002007	IBM_TDB	2004/00/12
-	1	20030030097.pn.	US-PGPUB	2004/08/13
-	0	("6781193").PN.	USPAT	2004/08/13
				12:40

_	0	("6781193").PN.	USPAT	2004/08/13
				12:40
-	215	mos adj1 diode and 257/\$\$\$.ccls.	USPAT;	2004/08/13
			US-PGPUB;	13:22
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	1606	257/357,360,364,365.ccls	USPAT;	2004/08/13
			US-PGPUB;	13:25
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	384	327/313,314,325.ccls.	USPAT;	2004/08/16
			US-PGPUB;	12:59
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	